# NSN 5961-01-274-5232

Transistor - Page 1 of 1





# **Inclosure Material:**

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

Between 0.250 inches and 0.450 inches

# **Overall Width:**

0.875 inches

#### **End Application:**

5895-01-205-0645 converter

#### Mounting Facility Quantity:

2

### Internal Configuration:

Field effect

Electrode Internally-electrically Connected To Case:

Drain

# Mounting Method:

Unthreaded hole

### Features Provided:

Burn in

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

-60.0 drain to source voltage and -60.0 drain to gate voltage

# **Current Rating Per Characteristic:**

-8.00 amperes drain current

# **Power Rating Per Characteristic:**

75.0 watts total device dissipation

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

#### **Special Features:**

Device requires special handling and processing to prevent damage from electrostatic discharge transients

#### **Terminal Type And Quantity:**

2 pin

### Shelf Life:

N/a

#### Unit Of Measure:

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### Demilitarization:

No

Fiig:

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